# Міскоснір МСР616/617/618/619

# 2.3V to 5.5V Micropower Bi-CMOS Op Amps

# FEATURES

- Low Power: I<sub>DD</sub> = 25 μA, max
- Low Offset Voltage: 150 μV, max
- Rail-to-Rail Swing at Output
- · Low Input Offset Current: 0.3 nA, typical
- Specifications rated for 2.3V to 5.5V Supplies
- Unity Gain Stable
- Chip Select (CS) Capability with MCP618
- Industrial Temperature range supported
- No Phase Reversal
- · Available in Single, Dual, and Quad

# APPLICATIONS

- Battery Powered Instruments
- Strain Gauges
- Medical Instruments
- Test Equipment

# AVAILABLE TOOLS

- Spice Macromodels (at www.microchip.com)
- FilterLab<sup>TM</sup> Software (at www.microchip.com)

# HISTOGRAM OF INPUT OFFSET VOLTAGE



# DESCRIPTION

The MCP616, MCP617, MCP618 and MCP619 from Microchip Technology, Inc. are unity gain stable, low offset voltage operational amplifiers capable of precision low power single supply operation. Performance characteristics include ultra low offset voltage (150  $\mu$ V, max.), rail-to-rail output swing capability, and low input offset current (0.3 nA typ.). These features make this family of amplifiers well suited for single supply precision, high impedance, battery powered applications.

The single MCP616 is available in standard 8-lead PDIP, SOIC, and MSOP packages. Another version of the single op amp, MCP618 is offered with a Chip Select (CS) option in standard 8-lead PDIP, SOIC, and MSOP packages. The dual MCP617 is offered in standard 8-lead PDIP, SOIC, as well as the MSOP package. Finally, the quad MCP619 is offered in 14-lead PDIP, SOIC and TSSOP packages. All devices are fully specified from -40°C to +85°C with power supplies from 2.3V to 5.5V.

# PACKAGES



# 1.0 ELECTRICAL CHARACTERISTICS

# 1.1 <u>Maximum Ratings</u>†

V <sub>DD</sub> 7.0V
All inputs and outputs w.r.t. $\\ V_{SS}$ –0.3V to $V_{DD}$ +0.3V
Difference Input voltage $\hfill \hfill \hf$
Output Short Circuit Currentcontinuous
Current at Input Pins±2 mA
Current at Output and Supply Pins±30 mA
Storage temperature65°C to +150°C
Ambient temp. with power applied55°C to +125°C
ESD protection on all pins (HBM) $\geq$ 4 kV

**† Notice:** Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

# **PIN FUNCTION TABLE**

Name	Function
+IN/+INA/+INB/+INC/+IND	Non-inverting Input
-IN/-INA/-INB/-INC/-IND	Inverting Input Terminals
V <sub>DD</sub>	Positive Power Supply
V <sub>SS</sub>	Negative Power Supply
OUT/OUTA/OUTB/OUTC/OUTD	Output Terminals
CS	Chip Select
NC	No internal connection to IC

# **DC CHARACTERISTICS**

Unless otherwise specified, all limits are specified, $V_{PP}/2$ and $V_{QUT} \sim V_{PP}/2$	cified for V <sub>DD</sub>	= +2.3V to +5.5	5V, V <sub>SS</sub> =	GND, T <sub>A</sub> = 25	°C, V <sub>CM</sub> =	$V_{DD}/2$ , $R_L = 100 \text{ k}\Omega$ to
PARAMETERS	SYM.	MIN.	TYP.	MAX.	UNITS	CONDITIONS
INPUT OFFSET						
Input Offset Voltage	Vos	-150	—	+150	μV	
Drift with Temperature	dV <sub>OS</sub> /dT	—	±2		μV/°C	T <sub>A</sub> = -40°C to +85°C
Power Supply Rejection	PSRR	86	105	—	dB	
INPUT BIAS CURRENT AND IMPEDANCE						
Input Bias Current	Ι <sub>Β</sub>	-35	-15	-5	nA	
Over Temperature	I <sub>B</sub>	-70	—		nA	$T_A$ = -40°C to +85°C
Input Offset Bias Current	I <sub>OS</sub>	—	±0.3	—	nA	
Common Mode Input Impedance	Z <sub>CM</sub>	—	600  4	—	MΩ  pF	
Differential Input Impedance	Z <sub>DIFF</sub>	_	3  2		MΩ  pF	
COMMON MODE						
Common-Mode Input Range	CMR	V <sub>SS</sub>		V <sub>DD</sub> -0.9	V	
Common-Mode Rejection Ratio	CMRR	80	100	—	dB	V <sub>DD</sub> = 5V, V <sub>CM</sub> = 0.0 to 4.1V
OPEN LOOP GAIN						
DC Open Loop Gain	A <sub>OL</sub>	100	120	_	dB	$R_L = 25 k\Omega$ to V <sub>DD</sub> /2, 50 mV < V <sub>OUT</sub> < (V <sub>DD</sub> - 50 mV)
DC Open Loop Gain	A <sub>OL</sub>	95	115	_	dB	$R_L = 5 k\Omega$ to V <sub>DD</sub> /2, 100 mV < V <sub>OUT</sub> < (V <sub>DD</sub> - 100 mV)
OUTPUT						
Maximum Output Voltage Swing	V <sub>OL</sub> , V <sub>OH</sub>	V <sub>SS</sub> + 0.015	—	$V_{DD} - 0.020$	V	$R_L = 25 \text{ k}\Omega \text{ to } V_{DD}/2$
	V <sub>OL</sub> , V <sub>OH</sub>	V <sub>SS</sub> + 0.045	—	$V_{DD} - 0.060$	V	$R_L = 5 k\Omega \text{ to } V_{DD}/2$
Linear Region Output Voltage Swing	V <sub>OL</sub> , V <sub>OH</sub>	V <sub>SS</sub> + 0.050	—	V <sub>DD</sub> – 0.050	V	$ \begin{array}{l} R_{L} = 25 \ k\Omega \ to \ V_{DD}/2, \\ A_{OL} \geq 100 \ dB \end{array} $
	$V_{OL}, V_{OH}$	V <sub>SS</sub> + 0.100	—	V <sub>DD</sub> - 0.100	V	$R_L = 5 k\Omega$ to V <sub>DD</sub> /2, A <sub>OL</sub> ≥ 95 dB
Output Short Circuit Current	I <sub>SC</sub>		±17		mA	V <sub>OUT</sub> = 2.75V, V <sub>DD</sub> = 5.5V
POWER SUPPLY						
Supply Voltage	Vs	2.3	—	5.5	V	
Quiescent Current Per Amplifier	Ι <sub>Q</sub>	12	19	25	μA	I <sub>O</sub> = 0

# **AC CHARACTERISTICS**

Unless otherwise specified, all limits are specified for $V_{DD}$ = +2.3V to +5.5V, $V_{SS}$ = GND, $T_A$ = 25°C, $V_{CM}$ = $V_{DD}/2$ , $R_L$ = 100 k $\Omega$ to $V_{DD}/2$ , and $V_{OUT} \sim V_{DD}/2$									
PARAMETERS	SYM.	MIN.	TYP.	MAX.	UNITS	CONDITIONS			
Gain Bandwidth Product	GBWP	—	190	—	kHz	G = 1, V <sub>DD</sub> = 5V, C <sub>L</sub> = 60 pF			
Phase Margin at Unity Crossing	θ	—	57	—	degrees	G = 1, V <sub>DD</sub> = 5V, C <sub>L</sub> = 60 pF			
Slew Rate	SR	—	0.08	—	V/µs	G = 1, V <sub>DD</sub> = 5V, C <sub>L</sub> = 60 pF			
Input Voltage Noise	En	—	2.2	—	μVp-p	f = 0.1 Hz to 10 Hz			
Noise Density	e <sub>n</sub>	—	32		nV/√Hz	f≥1 kHz			
Input Current Noise Density	i <sub>n</sub>	—	70	—	fA/√Hz	f≥1 kHz			

# SPECIFICATIONS FOR MCP618 CHIP SELECT (CS) FEATURE

Unless otherwise specified, all limits are specified for  $V_{DD}$  = +2.3V to +5.5V,  $V_{SS}$  = GND,  $T_A$  = 25°C,  $V_{CM}$  =  $V_{DD}/2$ ,  $R_L$  = 100 k $\Omega$ , and  $V_{OUT} \sim V_{DD}/2$ 

PARAMETERS	SYM.	MIN.	TYP.	MAX.	UNITS	CONDITIONS		
CS LOW SPECIFICATIONS								
CS Logic Threshold, Low	V <sub>IL</sub>	V <sub>SS</sub>	—	0.2 V <sub>DD</sub>	V	For entire V <sub>DD</sub> range		
CS Input Current, Low	I <sub>CSL</sub>	-1.0	0.01		μA	$\overline{\text{CS}} = 0.2 \text{V}_{\text{DD}}$		
CS HIGH SPECIFICATIONS								
CS Logic Threshold, High	V <sub>IH</sub>	0.8 V <sub>DD</sub>	—	V <sub>DD</sub>	V	For entire V <sub>DD</sub> range		
CS Input Current, High	I <sub>CSH</sub>	—	0.01	2	μA	CS = V <sub>DD</sub>		
CS Input High, GND Current	۱ <sub>Q</sub>	—	0.05	2	μA	CS = V <sub>DD</sub>		
Amplifier Output Leakage, CS High		—	0.01	—	μA	$\overline{\text{CS}} = 0.8 \text{V}_{\text{DD}}$		
DYNAMIC SPECIFICATIONS								
CS Low to Amplifier Output High Turn-on Time	t <sub>ON</sub>	_	9	100	μs	$\label{eq:cs_decomposition} \begin{split} \overline{\text{CS}} & \text{low} = 0.2 \text{V}_{\text{DD}}, \\ \text{V}_{\text{OUT}} = 0.9 \ \text{*V}_{\text{DD}}/2, \\ \text{G} = +1 \text{V}/\text{V} \end{split}$		
CS High to Amplifier Output High Z	t <sub>off</sub>		0.1	—	μs	$\label{eq:cs_dispersive} \begin{split} \overline{\text{CS}} \ \text{high} &= 0.8 \text{V}_{\text{DD}}, \\ \text{V}_{\text{OUT}} &= 0.1 \ ^* \text{V}_{\text{DD}} / 2, \\ \text{G} &= +1 \text{V} / \text{V} \end{split}$		
Hysteresis		—	0.6	_	V	V <sub>DD</sub> = 5V		

# **TEMPERATURE SPECIFICATIONS**

Unless otherwise specified, all limits are specified for $V_{DD}$ = +2.3V to +5.5V, $V_{SS}$ = GND								
PARAMETERS	SYM.	MIN.	TYP.	MAX.	UNITS	CONDITIONS		
TEMPERATURE RANGES								
Specified Temperature Range	T <sub>A</sub>	-40	—	+85	°C			
Operating Temperature Range	T <sub>A</sub>	-40	—	+85	°C			
Storage Temperature Range	T <sub>A</sub>	-65	_	+150	°C			
THERMAL PACKAGE RESISTANCE								
Thermal Resistance, 8L-PDIP	$\theta_{JA}$	—	85	—	°C/W			
Thermal Resistance, 8L-SOIC	$\theta_{JA}$	_	163	_	°C/W			
Thermal Resistance, 8L-MSOP	$\theta_{JA}$	—	206	—	°C/W			
Thermal Resistance, 14L-PDIP	$\theta_{JA}$	—	70	—	°C/W			
Thermal Resistance, 14L-SOIC	$\theta_{JA}$	—	120	—	°C/W			
Thermal Resistance, 14L-TSSOP	$\theta_{JA}$	_	100	_	°C/W			

# 2.0 TYPICAL PERFORMANCE CURVES

Note: Unless otherwise indicated,  $T_A = 25^{\circ}C$ ,  $V_{CM} = V_{DD} / 2$  and  $V_{OUT} \sim V_{DD}/2$ ,  $V_{SS} = GND$ 



**FIGURE 2-1:** Histogram of Offset Voltage with  $V_{DD} = 5.5V$ .



**FIGURE 2-2:** Histogram of Offset Voltage with  $V_{DD} = 2.3V$ .



**FIGURE 2-3:** Histogram of Input Bias Current with  $V_{DD} = 5.5V$ .



**FIGURE 2-4:** Histogram of Offset Voltage Drift with  $V_{DD} = 5.5V$ .



**FIGURE 2-5:** Histogram of Offset Voltage Drift with  $V_{DD} = 2.3V$ .



**FIGURE 2-6:** Histogram of Input Offset Current with  $V_{DD} = 5.5V$ .

**Note:** Unless otherwise indicated,  $T_A = 25^{\circ}C$ ,  $V_{CM} = V_{DD} / 2$  and  $V_{OUT} \sim V_{DD}/2$ ,  $V_{SS} = GND$ 



**FIGURE 2-7:** Normalized Offset Voltage vs. Temperature.



**FIGURE 2-8:** Quiescent Current vs. Temperature vs. Power Supply Voltage.



**FIGURE 2-9:** Maximum Output Voltage Swing vs. Temperature with  $R_L = 5 k\Omega$ .



**FIGURE 2-10:** Input Bias Current, Input Offset Current vs. Temperature.



FIGURE 2-11: Common Mode Rejection Ratio, Power Supply Rejection Ratio vs. Temperature.



**FIGURE 2-12:** Maximum Output Voltage Swing vs. Temperature with  $R_L = 25 k\Omega$ .

Note: Unless otherwise indicated,  $T_A = 25$  °C,  $V_{CM} = V_{DD} / 2$  and  $V_{OUT} \sim V_{DD}/2$ ,  $V_{SS} = GND$ 



FIGURE 2-13: Output Short Circuit Current vs. Temperature vs. Power Supply Voltage.



FIGURE 2-14: Slew Rate vs. Temperature.







**FIGURE 2-16:** Gain Bandwidth Product, Phase Margin vs. Temperature.



FIGURE 2-17: Input Offset Voltage vs. Common Mode Input Voltage vs. Temperature.



FIGURE 2-18: Input Offset Voltage vs. Output Voltage.

**Note:** Unless otherwise indicated,  $T_A = 25^{\circ}C$ ,  $V_{CM} = V_{DD} / 2$  and  $V_{OUT} \sim V_{DD}/2$ ,  $V_{SS} = GND$ 



FIGURE 2-19: Quiescent Current vs. Power Supply Voltage vs. Temperature.



FIGURE 2-20: DC Open Loop Gain vs. Load Resistance vs. Power Supply Voltage.



FIGURE 2-21: Gain Bandwidth Product, Phase Margin vs. Load Resistance.



**FIGURE 2-22:** Maximum Output Voltage Swing vs. Load Resistance.



FIGURE 2-23: DC Open Loop Gain vs. Power Supply Voltage.



FIGURE 2-24: Channel to Channel Separation vs. Frequency (MCP617 and MCP619 only).

# MCP616/617/618/619

Note: Unless otherwise indicated,  $T_A = 25$  °C,  $V_{CM} = V_{DD} / 2$  and  $V_{OUT} \sim V_{DD}/2$ ,  $V_{SS} = GND$ 







FIGURE 2-26: Input Voltage Noise Density vs. Frequency.



FIGURE 2-27: Small Signal Non-Inverting Pulse Response.



**FIGURE 2-28:** Common-Mode Rejection Ratio, Power Supply Rejection Ratio vs. Frequency.



FIGURE 2-29: Maximum Output Voltage Swing vs. Frequency.



FIGURE 2-30: Small Signal Inverting Pulse Response.

**Note:** Unless otherwise indicated,  $T_A = 25^{\circ}C$ ,  $V_{CM} = V_{DD} / 2$  and  $V_{OUT} \sim V_{DD}/2$ ,  $V_{SS} = GND$ 



**FIGURE 2-31:** Large Signal Non-Inverting Pulse Response.



FIGURE 2-32: Chip Select to Amplifier Output Response Time (MCP618 only).



**FIGURE 2-33:** Large Signal Inverting Pulse Response.



FIGURE 2-34: CS Hysteresis (MCP618 only).

# 3.0 APPLICATIONS INFORMATION

The MCP616/617/618/619 family of operational amplifiers are fabricated on Microchip's state-of-the-art CMOS process. They are unity gain stable and suitable for a wide range of general purpose applications. With this family of operational amplifiers, the power supply pin should be by-passed with a 0.1  $\mu$ F capacitor.

## 3.1 Rail-to-Rail Output Swing

There are two specifications that describe the output swing capability of the MCP616/617/618/619 family of operational amplifiers. The first specification, Maximum Output Voltage Swing, defines the absolute maximum swing that can be achieved under specified loaded conditions. For instance, the MCP616/617/618/619 family is specified to be able to swing at least to 15 mV from the negative rail with a 25 k $\Omega$  load to V<sub>DD</sub>/2. This output swing performance is shown in Figure 3-1, where the output of an MCP616 is configured in a gain of +2V/V and overdriven with a 4 kHz triangle wave.



FIGURE 3-1: Maximum Output Voltage Swing.

The second specification that describes the output swing capability of these amplifiers is the Linear Region Output Voltage Swing. This specification defines the maximum output swing that can be achieved while the amplifier is still operating in its linear region. For instance, the open loop gain is  $\geq$  100 dB for a 25 k $\Omega$  load over the specified range of  $V_{SS}$  +0.050V and  $V_{DD}$ -0.050V.

The classical definition of the DC open loop gain of an amplifier is:

$$A_{OL} = 20 \log_{10} \left( \frac{\Delta V_{OUT}}{\Delta V_{OS}} \right)$$

where:

A<sub>OL</sub> is the DC open loop gain of the amplifier

 $\Delta V_{OUT}$  is the change in  $V_{\rm OUT}$  while in the Linear Region Output Voltage swing spec

 $\Delta V_{OS}$  is the change in input offset voltage with the change in  $V_{\text{OUT}}$ 

## 3.2 Input Voltage and Phase Reversal

The MCP616/617/618/619 amplifier family is designed with CMOS devices and PNP input transistors. It is designed to not exhibit phase inversion when the input pins exceed the supply voltages. Figure 3-2 shows an input voltage exceeding both supplies with no resulting phase inversion.



**FIGURE 3-2:** The MCP616/617/618/619 family of op amps do not have phase reversal issues. For this graph, the amplifier is in a gain of +2V/V.

The maximum operating common-mode voltage that can be applied to the inputs is  $V_{SS}$  to  $V_{DD}$  -0.9V. In contrast, the absolute maximum input voltage is  $V_{SS}$  - 0.3V and  $V_{DD}$  + 0.3V. Voltages on the input that exceed this absolute maximum rating can cause excessive current to flow in or out of the input pins. Current beyond ±2 mA can cause possible reliability problems. Applications that exceed this rating must be externally limited with an input resistor as shown in Figure 3-3.



**FIGURE 3-3:** If the inputs of the amplifier exceed the Absolute Maximum Specifications, an input resistor,  $R_{IN}$ , should be used to limit the current flow into that pin.

# 3.3 Capacitive Load and Stability

Driving capacitive loads can cause stability problems with many of the higher speed amplifiers.

For any closed loop amplifier circuit, a good rule of thumb is to design for a phase margin that is no less than 45°. This is a conservative theoretical value, however, if the phase margin is lower, layout parasitics can degrade the phase margin further causing a truly unstable circuit. A system with 45° phase margin will have an overshoot in its step response of approximately 25%.

A buffer configuration with a capacitive load is the most difficult configuration for an amplifier to maintain stability. The Phase versus Capacitive Load of the amplifier is shown in Figure 3-4. In this figure, it can be seen that the amplifier has a phase margin above  $45^{\circ}$ , while driving capacitance loads up to 150 pF. This figure also shows that higher capacitive loads reduce the bandwidth of the amplifier.



**FIGURE 3-4:** Gain Bandwidth Product, Phase Margin vs. Capacitive Load.



**FIGURE 3-5:** Amplifier circuits that can be used when driving heavy capacitive loads.

If the amplifier is required to drive larger capacitive loads, the circuit shown in Figure 3-5 can be used. A small series resistor ( $R_{\rm ISO}$ ) at the output of the amplifier improves the phase margin when driving large capacitive loads. This resistor decouples the capacitive load from the amplifier by introducing a zero in the transfer function. It will not, however, significantly improve the bandwidth for larger capacitive loads.

This zero adjusts the phase margin by approximately:

$$\Delta \theta_m = \tan^{-1} (2\pi GBWP \times R_{ISO} \times C_L)$$

where:

 $\Delta \theta_m$  is the improvement in phase margin,

*GBWP* is the gain bandwidth product of the amplifier,

 $R_{ISO}$  is the capacitive decoupling resistor, and  $C_L$  is the load capacitance

# 3.4 DC Offsets

The MCP616/617/618/619 amplifier family has very low offset voltage (150  $\mu$ V max at T<sub>A</sub> = 25°C). These amplifiers use a PNP transistor input stage with a typical bias currents of -15 nA, which must have a DC path to ground or the op amp will not bias properly. The DC resistances seen by the op amp inputs (R<sub>2</sub> and R<sub>F</sub>||R<sub>1</sub> in Figure 3-6) need to be equal to minimize DC offsets. Also keep these resistance ≤100 kΩ for low DC offset.



FIGURE 3-6: Circuit for calculating DC Offset.

To calculate the DC offset ( $\Delta V_{OUT})$ , first simplify the circuit to its DC equivalent.

- · Replace capacitors with open circuits
- · Replace inductors with short circuits
- · Replace AC voltage sources with short circuits
- · Replace AC current sources with open circuits
- Convert DC sources and resistances into Thieving equivalent form

Second, calculate the nominal DC bias point. Note that current is positive going into the op amp, so the bias current spec shows current sourced out of the inputs.

Where:

 $V_{\rm CM}$  is the common mode voltage at the op amp inputs

 $G_N$  is the DC gain from the non-inverting input to  $V_{OUT}$ 

Third, calculate the DC error voltage caused by the op amp.

$$\Delta V_{OUT} = G_N V_{OS} + G_N I_B (R_F || R_1 - R_2) -G_N I_{OS} \frac{R_F || R_1 + R_2}{2}$$

Last, use the values in the DC Characteristics table to determine the worst case V<sub>OUT</sub> +  $\Delta$ V<sub>OUT</sub> for your design. Make sure that the output voltage range is not exceeded.

Note that with very high input DC resistances, the output may exceed the linear region output voltage swing specification, and the op amp will saturate. Keep the input resistances below 100 k $\Omega$  to help prevent this from happening.

#### 3.5 The Chip Select Option of the MCP618

The MCP618 is a single amplifier with a Chip Select  $(\overline{CS})$  option. When  $\overline{CS}$  is pulled high the supply current drops to 50 nA (typ). In this state, the amplifier is put into a high impedance state. By pulling  $\overline{CS}$  low, the amplifier is enabled. If the  $\overline{CS}$  pin is left floating, the amplifier will not operate properly. Figure 3-7 shows the output voltage and supply current response to a  $\overline{CS}$  pulse.



FIGURE 3-7: Timing Diagram for the CS Function of the MCP618 Amplifier.

## 3.6 Layout Considerations

Good PC board layout techniques will help you achieve the performance shown in the specs and Typical Performance Curves. It will also help you minimize EMC (Electro-Magnetic Compatibility) issues.

#### 3.6.1 COMPONENT PLACEMENT

Partition the board layout into different sections to minimize crosstalk. Digital and analog functions should be separated from each other. High speed and low speed parts should be kept apart whenever possible.

Keep important signal traces as short as possible, especially high frequency (low rise time) signals. This reduces the signal's exposure to interference. Other traces, such as supply lines, can be longer. Place analog parts in the signal path close together.

Use a  $0.1 \,\mu\text{F}$  supply bypass capacitor within 0.1" (2.5 mm) of the V<sub>DD</sub> pin. It should connect directly to the ground plane, in order to minimize ground loops.

#### 3.6.2 SIGNAL COUPLING

The input pins of the MCP616/617/618/619 amplifiers are high impedance, which allows noise injection if good layout techniques are not followed. Current can be injected into the inputs from another trace with fast changing voltages, such as digital clock. This current is coupled capacitively between the traces.



**FIGURE 3-8:** Capacitors can be built with PCB traces, allowing signals to couple from one trace to another.

The PCB layout shown in Figure 3-8 produces parasitic capacitances as shown in Figure 3-9. The resistor  $R_{T2}$  includes the op amp input resistance, and any additional resistance the designer ties from the trace to ground.



FIGURE 3-9: Equivalent circuit for Figure 3-8.

The signal, V<sub>1</sub> is coupled to the sensitive trace through the mutual capacitance, C<sub>M</sub>. The terminating resistor, R<sub>T2</sub> attenuates the coupled signal at low frequencies, and the shunt capacitor, C<sub>SH2</sub> at high frequencies. Without the ground plane (C<sub>SH2</sub> = 0), V<sub>1</sub> would appear without attenuation on the sensitive trace at high frequencies. The capacitances C<sub>M</sub>, C<sub>SH1</sub> and C<sub>SH2</sub> can be approximated with these formulas:

$$C_{M} \approx \frac{h_{T} L \varepsilon_{0} \varepsilon_{i}}{d}$$
$$C_{SH1} = C_{SH2} \approx \frac{L w \varepsilon_{0} \varepsilon_{r}}{h_{d}}$$

Where:

 $V_1$  = interfering voltage signal

 $C_M$  = mutual capacitance

 $C_{SH1}$  = shunt capacitance at V<sub>1</sub>

 $C_{SH2}$  = shunt capacitance at sensitive trace

 $R_{T2}$  = optional terminating resistance attached to sensitive trace

To reduce this capacitively coupled signal,

- 1. Always use ground plane.
  - a. Put ground plane and sensitive traces in adjacent PCB layers.
  - b. Inject large currents into the ground plane far away from sensitive traces.
- 2. Minimize interfering signal strength.
  - a. Keep the edge rates on digital signals low.
  - b. Limit the bandwidth of analog signals.
  - c. Keep interfering traces far apart.
  - d. Minimize distance interfering traces are in parallel.
- 3. Dissipate interfering signals at sensitive traces.
  - a. Make sensitive traces as wide and short as possible.
  - b. Connect a low-valued shunt resistor from sensitive trace to ground.

## 3.7 <u>Typical Applications</u>

#### 3.7.1 HIGH GAIN PRE-AMPLIFIER

The MCP616/617/618/619 amplifiers are well suited to amplifying small signals produced by low impedance sources/sensors. The low offset voltage, low offset current, and low noise fit well in this role. Figure 3-10 shows a typical pre-amplifier connected to a low impedance source (V<sub>S</sub> and R<sub>S</sub>).



**FIGURE 3-10:** High gain pre-amplifier for low resistance sources.

For the best noise and offset performance, the source resistance  $R_{S}$  needs to be  ${\leq}15~k\Omega.$  The DC resistances at the inputs are equal to minimize the offset voltage caused by the input bias currents. In this circuitry, the DC gain is 10V/V, which will give a typical bandwidth of 16 kHz.

#### 3.7.2 TWO OP AMP INSTRUMENTATION AMPLIFIER

The two op amp instrumentation amplifier shown in Figure 3-11 serves the function of taking the difference of two input voltages, level shifting then and providing a single output. This configuration is best suited for higher gains. The key specifications that make the MCP616/617/618/619 family appropriate for this application circuit is low offset voltage and high common-mode rejection. The reference voltage ( $V_{REF}$ ) of this circuit is supplied to the first op amp in the signal chain. Typically, this voltaged is half of the supply voltage in a single supply environment.



FIGURE 3-11: Two Op Amp Instrumentation Amplifiers.

# 3.7.3 THREE OP AMP INSTRUMENTATION AMPLIFIER

A classic, three op amp instrumentation amplifier is illustrated in Figure 3-12. The input operational amplifiers in this circuit provide signal gain. The output operational amplifier converts the signal from two inputs to a single ended output with a difference amplifier. The gain of this circuit is simply adjusted with one resistor,  $R_G$ . The reference voltage ( $V_{\text{REF}}$ ) of the difference stage of this instrumentation amplifier is capable of spanning a wide range. Most typically, this node is referenced to half of the supply voltage in a signal supply application.



**FIGURE 3-12:** Three Op Amp Instrumentation Amplifiers.

# 3.7.4 PRECISION GAIN WITH GOOD LOAD ISOLATION

In Figure 3-13, the low input offset voltage of the MCP616 is used to implement a circuit with a high gain. This precision measurement can easily be disrupted by changing the output current drive of the device that is doing the amplification work. Consequently, the precision amplifier configuration is followed by a MCP601 amplifier which is capable of driving higher currents. Since the two amplifiers are housed in separate packages, there is minimal change in offset voltage of the MCP616 due to loading effects.



FIGURE 3-13: Precision Gain with Good Load Isolation.

# 4.0 SPICE MACROMODEL

The Spice macromodel for the MCP616, MCP617, MCP618 and MCP619 simulates the typical amplifier performance of offset voltage, DC power supply rejection, input capacitance, DC common mode rejection ratio, open loop gain over frequency, phase margin with no capacitive load, output swing, DC power supply current, power supply current change with supply voltage, input common mode range and input voltage noise.

The characteristics of the MCP616, MCP617, MCP618, and MCP619 amplifiers are similar in terms of performance and behavior. This single op amp macromodel supports all four devices with the exception of the chip select  $(\overline{CS})$  function of the MCP618, which is not modeled.

The listing for this macromodel is shown on the next page. The most recent revision of the model can be downloaded from Microchip's web site at www.microchip.com

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```
.SUBCKT MCP616 1 2 3 4 5
*
               | | Output
                | | Negative Supply
                | Positive Supply
               | Inverting Input
              Non-inverting Input
* Macromodel for MCP616 (single), MCP617 (dual), MCP618 (single w/CS), and MCP619 (quad)
* The characteristics of the MCP616, MCP617, MCP618, and MCP619 have the same fundamental
* performance and behavior. Consequently, this single op amp macromodel supports all four
* devices. However, the chip select function of the MCP618 is not modeled.
* Revision History:
   REV A : 2-23-01 created KEB
* This macromodel models typical amplifier offset voltage, DC power supply rejection, input
* capacitance, open loop gain over frequency, phase margin with 60pF load, output swing,
* power supply current, input voltage noise, slew rate.
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*Input Stage, pole at 300kHz
01
      964 7 PQ
      8 2
            7
02
               PO
         2 2P
CDM
      1
      1 2 400P
TOS
CCM1 1 4 4P
CCM2
     2 4 4P
IDD
     3 7 13.3U
DCT
     20 3 DX
VCT
    20 7 1.10
      8 6 5.53K
RA
RB
      9
         6 5.53K
      8 9 48.0P
CA
VCMM 4 6 0.45
ICOMP 4 3 195U
```

# MCP616/617/618/619

```
* Input Stage Common-Mode Clamping
ECM 55 4 3 64 1
RCM 57 56 1K
DCMP 56 55 DY
VCMP 57 4 1.2
RST 58 59 1K
DST 59 55 DX
VST 58 4 1.6
GCMP2 23 4 POLY(2) 57 56 58 59 0 0 0;0 -500U 500U
*
* Input Errors (vos, en, psr)
*
ERR 64 1 poly(2) 67 4 3 4 -50U 2.3 6U
*
* Second Stage, pole at 0.19Hz
GS
     23 4 8 9 181U
R1
     23 4 5.53G
   23 4 166P
C2
VSOM 3 24 4.784
VSOP 25 4 -3.98
DSOM 23 24 DY
DSOP 25 23 DY
*HCM 23 3 VCMP
FS
   3 4 POLY(11) VO3 VO5 VO4 VO6 VO1 VO2 VO9 VO10 VMID1 VSOP VSOM
+ 200U -1 -1 -1 1 -1 -1 1 1 -1 -1 -1 -1
* Mid-supply Reference
*
RMID1 3 35 61.62K
VMID1 35 34 0
RMID2 4 34 61.62K
ELEVEL 34 4 23 4 -1
* Output Stage
*
DO3
    34 43 DY
    44 34 DY
DO4
DO5
      3 45 DY
D06
      3 46 DY
DO7
      4 45 DY
DO8
      4 46 DY
VO3
      43 5 0.1
VO4
      544 30M
GO5
      3 47 3 34 10M
VO5
     47 5 0
G06
      4 48 34 4 10M
V06
     48 5 0
G01
     49 4 5 34 10M
VO1
     49 45 0
GO2
      50 4 34 5 10M
     50 46 0
VO2
      3 51 100
RO9
    51 5 0
VO9
RO10 52 4 100
VO10 52 5 0
```

# MCP616/617/618/619

```
*
* Input Voltage Noise
VN1 65 4 0.6
DN1 65 67 DX
RN1 67 4 10K
*
* Models
*
.model PQ PNP (IS=0.1F BF=440 VAF=70 RB=1K)
.model DY D (IS=1F BV=50)
.model DX D (IS=0.001F AF=1.0 KF=55F)
*
.ENDS MCP616
```

# 5.0 PACKAGING INFORMATION

## 5.1 Package Marking Information



8-Lead SOIC (150 mil)



#### 8-Lead MSOP



Example: MCP616 I/PNNN SYVWW J LJ LJ LJ



#### Example:



Legenc	I: XXX YY WW NNN	Customer specific information* Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code
Note:	In the ever be carried for custom	nt the full Microchip part number cannot be marked on one line, it will over to the next line thus limiting the number of available characters er specific information.

\* Standard marking consists of Microchip part number, year code, week code, traceability code (facility code, mask rev#, and assembly code). For marking beyond this, certain price adders apply. Please check with your Microchip Sales Office.

#### Package Marking Information (Continued)



Legenc	I: XXX YY WW NNN	Customer specific information* Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code
Note:	In the ever be carried for custom	nt the full Microchip part number cannot be marked on one line, it will over to the next line thus limiting the number of available characters er specific information.

\* Standard marking consists of Microchip part number, year code, week code, traceability code (facility code, mask rev#, and assembly code). For marking beyond this, certain price adders apply. Please check with your Microchip Sales Office.

8-Lead Plastic Dual In-line (P) – 300 mil (PDIP)







	Units	INCHES*			MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.360	.373	.385	9.14	9.46	9.78
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing §	eB	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

\* Controlling Parameter § Significant Characteristic

Notes:

Notes: Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-001 Drawing No. C04-018

# 8-Lead Plastic Small Outline (SN) – Narrow, 150 mil (SOIC)









	Units		INCHES*			MILLIMETERS		
Dimension	MIN	NOM	MAX	MIN	NOM	MAX		
Number of Pins	n		8			8		
Pitch	р		.050			1.27		
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75	
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55	
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25	
Overall Width	ш	.228	.237	.244	5.79	6.02	6.20	
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99	
Overall Length	D	.189	.193	.197	4.80	4.90	5.00	
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51	
Foot Length	L	.019	.025	.030	0.48	0.62	0.76	
Foot Angle	¢	0	4	8	0	4	8	
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25	
Lead Width	В	.013	.017	.020	0.33	0.42	0.51	
Mold Draft Angle Top	α	0	12	15	0	12	15	
Mold Draft Angle Bottom	β	0	12	15	0	12	15	

\* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-012 Drawing No. C04-057

# 8-Lead Plastic Micro Small Outline Package (MS) (MSOP)









	Units	INCHES			MILLIMETERS*				
Dimension L	imits	MIN	NOM	MAX	MIN	NOM	MAX		
Number of Pins	n		8				8		
Pitch	р		.026			0.65	0.65		
Overall Height	А			.044			1.18		
Molded Package Thickness	A2	.030	.034	.038	0.76	0.86	0.97		
Standoff §	A1	.002		.006	0.05		0.15		
Overall Width	Е	.184	.193	.200	4.67	4.90	.5.08		
Molded Package Width	E1	.114	.118	.122	2.90	3.00	3.10		
Overall Length	D	.114	.118	.122	2.90	3.00	3.10		
Foot Length	L	.016	.022	.028	0.40	0.55	0.70		
Footprint (Reference)	F	.035	.037	.039	0.90	0.95	1.00		
Foot Angle	¢	0		6	0		6		
Lead Thickness	С	.004	.006	.008	0.10	0.15	0.20		
Lead Width	В	.010	.012	.016	0.25	0.30	0.40		
Mold Draft Angle Top	α		7			7			
Mold Draft Angle Bottom	β		7			7			

\*Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

Drawing No. C04-111

14-Lead Plastic Dual In-line (P) – 300 mil (PDIP)



	Units	INCHES*			MILLIMETERS		
Dimension	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		14			14	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	E	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.740	.750	.760	18.80	19.05	19.30
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing §	eB	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

\* Controlling Parameter § Significant Characteristic

Notes: Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side. JEDEC Equivalent: MS-001 Drawing No. C04-005

14-Lead Plastic Small Outline (SL) - Narrow, 150 mil (SOIC)



	Units	INCHES*		MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		14			14	
Pitch	р		.050			1.27	
Overall Height	А	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	E	.228	.236	.244	5.79	5.99	6.20
Molded Package Width	E1	.150	.154	.157	3.81	3.90	3.99
Overall Length	D	.337	.342	.347	8.56	8.69	8.81
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.016	.033	.050	0.41	0.84	1.27
Foot Angle	φ	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.014	.017	.020	0.36	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

\* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-012

Drawing No. C04-065

14-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm (TSSOP)



	Units	INCHES		MILLIMETERS*			
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		14			14	
Pitch	р		.026			0.65	
Overall Height	Α			.043			1.10
Molded Package Thickness	A2	.033	.035	.037	0.85	0.90	0.95
Standoff §	A1	.002	.004	.006	0.05	0.10	0.15
Overall Width	ш	.246	.251	.256	6.25	6.38	6.50
Molded Package Width	E1	.169	.173	.177	4.30	4.40	4.50
Molded Package Length	D	.193	.197	.201	4.90	5.00	5.10
Foot Length	L	.020	.024	.028	0.50	0.60	0.70
Foot Angle	φ	0	4	8	0	4	8
Lead Thickness	С	.004	.006	.008	0.09	0.15	0.20
Lead Width	B1	.007	.010	.012	0.19	0.25	0.30
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

\* Controlling Parameter § Significant Characteristic

Notes: Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side. JEDEC Equivalent: MO-153

Drawing No. C04-087

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PART NO.	¥	<u>/xx</u>	Examples:
Device	Temperature Range	Package	<ul> <li>a) MCP616-I/P Industrial Temp., PDIP package</li> <li>b) MCP616-I/SN Industrial Temp., SOIC package</li> <li>c) MCP616T-I/SN Tape and Reel, Industrial Temp. SOIC package</li> </ul>
Temperature Range	MCP616 = MCP616T = MCP617T = MCP618 = MCP618T = MCP619 = MCP619T =	Single Operational Amplifier Single Operational Amplifier (Tape and Reel-SOIC/MSOP) Dual Operational Amplifier Dual Operational Amplifier (Tape and Reel-SOIC/MSOP) Single Operational Amplifier w/CS Function Single Operational Amplifier w/CS Function (Tape and Reel-SOIC/MSOP) Quad Operational Amplifier Quad Operational Amplifier (Tape and Reel-SOIC/TSSOP) 40°C to +85°C	<ul> <li>d) MCP616-I/MS Industrial Temp., MSOP package</li> <li>e) MCP616T-I/MS Tape and Reel, Industrial Temp., MSOP package</li> <li>f) MCP617-I/P Industrial Temp., PDIP package</li> <li>g) MCP618-I/SN Industrial Temp., SOIC package</li> <li>h) MCP618T-I/SN Tape and Reel, Industrial Temp., SOIC package</li> <li>i) MCP619-I/P Industrial Temp. PDIP package</li> <li>i) MCP619-I/P Industrial Temp. PDIP package</li> </ul>
Package	P = SN = SL = ST = MS =	Plastic DIP (300 mil Body), 8-lead & 14-lead Plastic SOIC (150 mil Body), 8-lead Plastic SOIC (150 mil Body), 14-lead Plastic TSSOP, 14-lead Plastic MSOP, 8-lead	age

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